

Approved		Charged
<i>H. Kiyosue</i>		KISHIDA

Customer Approval	Approved	

Specification proposal

(2.5Gbps. APD Preamp Module Vcc=+3.3V)

FU-319SPA-6M20/V6M20/W6M20

PRELIMINARY

mitsubishi electric corp.

A	B	C	D
	x		
Date		Approved	
1.Mar.'02		H.Kiyosue	

PRELIMINARY

MITSUBISHI (OPTICAL DEVICES)

FU-319SPA-6M20/V6M20/W6M20**InGaAs APD PREAMP MODULE FOR THE 1.31 μm AND 1.55 μm WAVELENGTH RANGE****DESCRIPTION**

FU-319SPA-6M20/V6M20/W6M20 is InGaAs avalanche photodiode module with SiGe preamplifier, designed for use in high-speed, long haul optical communication systems.

The coaxial package contains InGaAs avalanche photodiode coupled with single-mode fiber pigtail and SiGe preamplifier.

FEATURES

- High-sensitivity (-33dBm typ)
- 5pin coaxial package
- Single power supply voltage +3.3V.
- Differential output (50 Ω)

APPLICATION

2.5Gbps.optical receiver (OC-48, STM-16)

Extended reach datacom and telecom applications

Long haul optical communication systems

ABSOLUTE MAXIMUM RATINGS (Tc=25°C)

Parameter	Symbol	Rating	Unit
APD Reverse voltage	VPD	0~Vbr	V
APD Reverse current (CW)	I _r	2	mA
APD Forward current (CW)	I _f	2	mA
Power supply voltage	VCC	-0.5~6	V
Operating case temperature	T _c	-40~+85	°C
Storage temperature	T _{stg}	-40~+85	°C

Vbr: APD breakdown voltage.

FU-319SPA-6M20/V6M20/W6M20

InGaAs APD PREAMP MODULE FOR THE 1.31 μm AND 1.55 μm WAVELENGTH RANGE

ELECTRICAL/OPTICAL CHARACTERISTICS (Tc=25°C, $\lambda=1.55\mu\text{m}$, VCC=3.3V, unless otherwise noted)

Parameter	Symbol	Test Conditions	Limits			Unit
			Min.	Typ.	Max.	
Detection range	-	-	1000	-	1600	nm
Responsivity	R13	CW, $\lambda=1.3\mu\text{m}$, M=1	0.7	0.85	-	A/W
	R15	CW, $\lambda=1.55\mu\text{m}$, M=1	0.8	0.9	-	
Breakdown voltage	Vbr	Id=100 μA	35	-	75	V
Temp.coefficient of Vbr (Note 3)	γ	Id=100 μA , Tc=-40~85°C	0.07	0.12	0.16	V/°C
Transimpedance	Zt	AC, f=200MHz, RL=50 Ω , Pin=-27 dBm, M=10, Single end, (Note 1)	1.0	1.37	1.75	k Ω
Maximum output voltage	Vod_max	AC, RL=50 Ω , Pin=-10dBm, M=10, Single end,	75	150	310	mV
Cutoff frequency(-3dB)	fc_High	AC, RL=50 Ω , M=10	1.6	1.9	-	GHz
	fc_Low	AC, RL=50 Ω	-	30	100	kHz
Average input equivalent noise current density	in	AC, RL=50 Ω , 1MHz~1.6GHz	-	10	-	pA/ $\sqrt{\text{Hz}}$
Output impedance	Zo	(Differential output)	-	50	-	Ω
Sensitivity	Pr	AC, RL=50 Ω , $\lambda=1.55\mu\text{m}$, NRZ, 2.48832Gbps., PRBS=2 ²³ -1, BER=10 ⁻¹⁰ , VPD=Optimum value (Note 2)	-	-33	-31	dBm
Over load power	Po		-7	-5	-	
Power supply voltage	VCC	-	3.1	3.3	3.5	V
Power supply current	ICC	VCC=3.3V	-	35	60	mA
Optical return loss	Prtn	$\lambda=1.55\mu\text{m}$	27	-	-	dB

Note 1. Zt=OUTN/Iin Iin:Preamp input current amplitude.

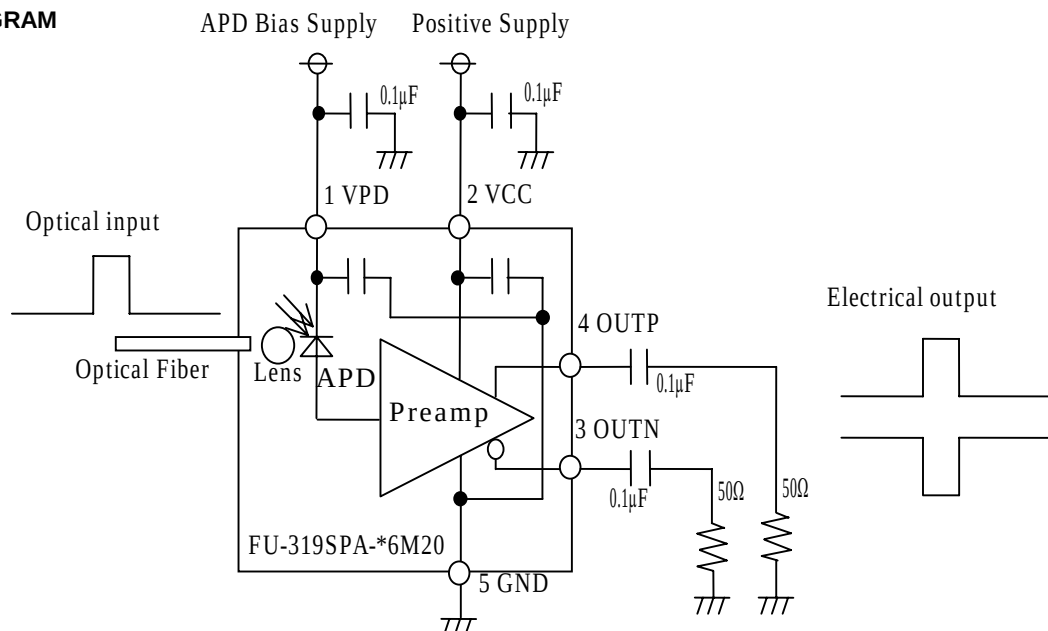
Note 2. Used post-amp bandwidth is 1.86GHz, Laser source extinction ratio is 10dB.

Note 3. $\gamma=(V_{br}(25^\circ\text{C}+\Delta T)-V_{br}(25^\circ\text{C}))/\Delta T$ [V/°C]

OPTICAL FIBER SPECIFICATION

Parameter	Limits			Unit
	FU-319SPA-6M20	FU-319SPA-V6M20	FU-319SPA-W6M20	
From of fiber end on delivery	Cut or ferrule	FC/PC connector	SC/PC connector	-
Type	SM			-
Mode field dia.	9.5 $\pm$ 1			μm
Cladding dia.	125 $\pm$ 2			μm
Jacket dia.	0.9 typ.			mm
Connector return loss	40(min)			dB

BLOCK DIAGRAM



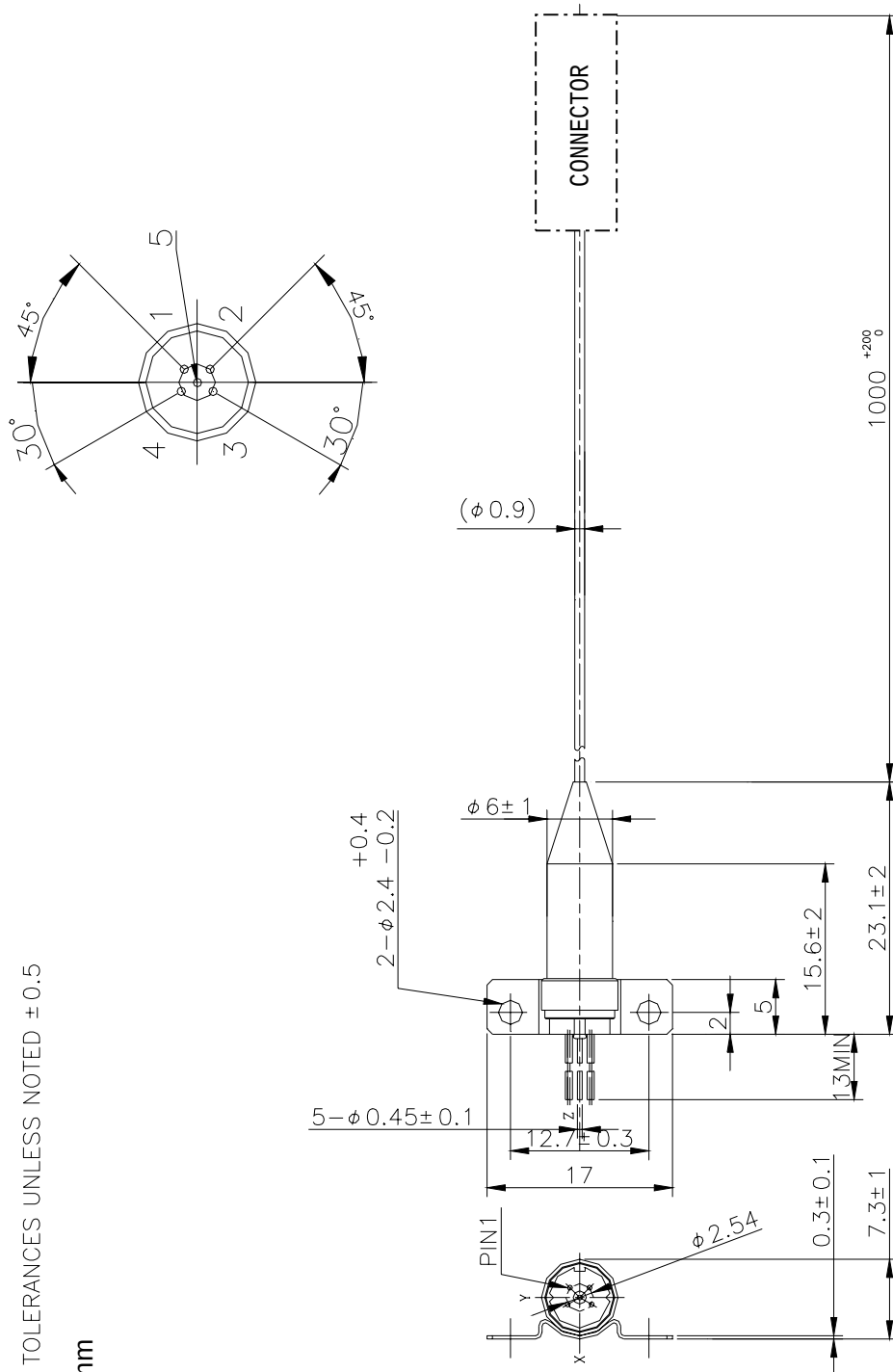
PRELIMINARY

TZ7-02-132A(4/4)

mitsubishi (optical devices)

FU-319SPA-6M20/V6M20/W6M20

InGaAs APD PREAMP MODULE FOR THE 1.31 μm AND 1.55 μm WAVELENGTH RANGE



Note 1. TOLERANCES UNLESS NOTED ± 0.5

UNIT:mm

- 1: VPD
- 2: VCC
- 3: OUTN
- 4: OUTP
- 5: GND